

# Crystal structure of HgGa<sub>2</sub>Se<sub>4</sub> under compression

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## Abstract

We report on high-pressure x-ray diffraction measurements up to 17.2 GPa in mercury digallium selenide ( $\text{HgGa}_2\text{Se}_4$ ). The equation of state and the axial compressibilities for the low-pressure tetragonal phase have been determined and compared to related compounds.  $\text{HgGa}_2\text{Se}_4$  exhibits a phase transition on upstroke towards a disordered rock-salt structure beyond 17 GPa, while on downstroke it undergoes a phase transition below 2.1 GPa to a phase that could be assigned to a metastable zinc-blende structure with a total cation-vacancy disorder. Thermal annealing at low- and high-pressure shows that kinetics plays an important role on pressure-driven transitions.

### Keywords:

- A. Chalcogénides
- C. High-pressure
- C. X-ray diffraction
- D. Crystal structure
- D. Phase transitions

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## 56 **1. Introduction**

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58 Mercury digallium selenide ( $\text{HgGa}_2\text{Se}_4$ ) is one of the less studied adamantine-  
59 type  $A^{\text{II}}B_2^{\text{III}}X_4^{\text{VI}}$  ordered-vacancy compounds (OVCs). It crystallizes in the tetragonal  
60 defect-chalcopyrite (DC) structure with space group (SG) I-4,  $Z=2$  [see **Fig. 1(a)**].  
61 Adamantine OVCs are tetrahedrally-coordinated semiconductors which have an  
62 unoccupied cationic site [1, 2]. The presence of vacancies results in a complex physics  
63 and explains why OVCs have been scarcely studied. A common feature of them is that  
64 they have several non-equivalent tetrahedrally-coordinated cations resulting in a  
65 distortion of the crystal lattice from the cubic symmetry. This fact, their anisotropy, and  
66 their band-gap energies make them suitable for many technological applications [3, 4].

67 High-pressure (HP) studies on  $A^{\text{II}}B_2^{\text{III}}X_4^{\text{VI}}$  compounds are receiving increasing  
68 attention in the last years [3-20]. In particular, ternary selenide compounds have been  
69 recently studied [3, 4, 6 - 10, 12 - 20]. However, to our knowledge, only one work has  
70 been devoted to  $\text{HgGa}_2\text{Se}_4$  [3], being focused on optical properties. In order to improve  
71 the knowledge of the HP behaviour of  $AGa_2\text{Se}_4$  compounds, we report here synchrotron  
72 XRD measurements in  $\text{HgGa}_2\text{Se}_4$ . In particular, we show evidence of the presence of  
73 two new phases. They can be probably assigned to a disordered rock-salt (DR) structure  
74 (SG: Fm-3m,  $Z=1$ ) [see **Fig. 1(b)**] and a disorder zinc-blende (DZ) structure (SG: F-  
75 43m,  $Z=1$ ) [see **Fig. 1(c)**].

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## 77 **2. Experimental section**

78 Single crystals of DC- $\text{HgGa}_2\text{Se}_4$  have been grown from its constituents HgSe  
79 and  $\text{Ga}_2\text{Se}_3$  by chemical vapor transport method using iodine as a transport agent [21].  
80 Chemical and structural analyses have shown the stoichiometric composition of the